IN THE U.S. PATENT AND TRADEMARK OFFICE

) Art Unit: 2823 ) Examiner: B. Kebede

Docket No: 0756-2330

unpei YAMAZAKI et al RIAL NO. 09/894,125

RE PATENT APPLICATION OF:

FILED: 06/29/2001

FOR: CRYSTALLINE SEMICONDUCTOR

THIN FILM, METHOD OF )

FABRICATING THE SAME,

SEMICONDUCTOR DEVICE AND )

METHOD OF FABRICATING THE SAME)

## PRELIMINARY AMENDMENT

Honorable Commissioner for Patents

U.S. Patent and Trademark Office

Washington, D.C. 20231

Sir:

Please preliminarily amend the above identified patent application as follows:

## IN THE SPECIFICATION

Please amend the specification as follows:

## Page 16, Paragraph 6, continuing on Page 17

The present invention can be also carried out when an active matrix type electrooptical device such as a liquid crystal display or an organic EL (electroluminescence) display device is fabricated.

12/20/2001 CV0111 00000074 09894125

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252.00 DP

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